

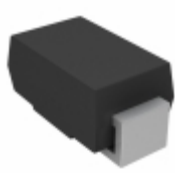
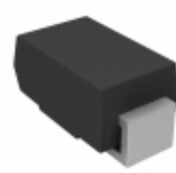


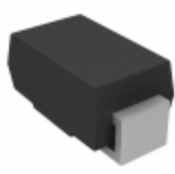
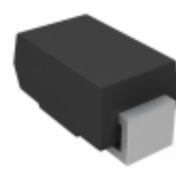

	<p>S1MHE3_A/I</p>
	<p>Hersteller-Teilenummer: S1MHE3_A/I</p> <p>Hersteller / Marke: Vishay / Semiconductor - Diodes Division</p> <p>Teil der Beschreibung: DIODE GEN PURP 1KV 1A DO214AC</p> <p>Datenblätter:  S1MHE3_A/I.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 97500 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	S1MHE3_A/I
Hersteller	Vishay / Semiconductor - Diodes Division
Beschreibung	DIODE GEN PURP 1KV 1A DO214AC
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	97500 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AC, SMA
Supplier Device-Gehäuse	DO-214AC (SMA)
Diodentyp	Standard
Strom - Richt (Io)	1A
Spannung - Forward (Vf) (Max) @ If	1.1V @ 1A
Strom - Sperrleckstrom @ Vr	5µA @ 1000V
Spannung - Sperr (Vr) (max)	1000V (1kV)
Geschwindigkeit	Standard Recovery >500ns, > 200mA (Io)
Rückwärts-Erholzeit (Trr)	1.8µs
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	12pF @ 4V, 1MHz
Verpackung	Tape & Reel (TR)




































S1MHE3_A/I ist neu im Original, Suche S1MHE3_A/I Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie S1MHE3_A/I Vishay / Semiconductor - Diodes Division mit Garantie und Vertrauen. Anfrage S1MHE3_A/I: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>S1ML TSC S1ML TSC</p>	 <p>S1MHE3/61T Electro-Films (EFI) / Vishay DIODE GEN PURP 1KV 1A DO214AC</p>	 <p>S1MHE3_A/H Electro-Films (EFI) / Vishay DIODE GEN PURP 1KV 1A DO214AC</p>	 <p>S1ML M2G TSC (Taiwan Semiconductor) DIODE GEN PURP 1000V 1A SUB SMA</p>
 <p>S1MHM2G TSC (Taiwan Semiconductor) DIODE GEN PURP 1000V 1A DO214AC</p>	 <p>S1MHE3/5AT Electro-Films (EFI) / Vishay DIODE GEN PURP 1KV 1A DO214AC</p>	 <p>S1MHE3_A/I Electro-Films (EFI) / Vishay DIODE GEN PURP 1KV 1A DO214AC</p>	 <p>S1MHR3G TSC (Taiwan Semiconductor) DIODE GEN PURP 1000V 1A DO214AC</p>

heiße Teile

Mehr

- | | | | | |
|--|--|---|--|---|
|  06035C272JAT4A |  AD6622AS |  AP1084D25L-13 |  B72650M200K72 |  BH6799FVM-GTR |
|  CMMSH1-100GTR |  EPCQ64SI16N |  G6J-2FS-Y-5VDC |  HAT3032R-EL |  IDTQS316211PA |
|  INA220AIDGT |  IP-J64-CY |  LC1206CB3TR18 |  LQM2HPN1R0MG0L |  LQP03TN56NJ02D |
|  LT1054ACS8#TRPBF |  LT1120CS8#PBF |  MAX14526EWP+T |  MAX1483EEPA |  MAX4533CAP+ |
|  MAX481ECSA+T |  MEM1608D201RT001 |  MMSZ4681-GS08 |  PACDN042 |  S1M-13-F |
|  S1M-E3/5AT |  S1M-E3/5AT |  S1M-E3/61T |  S1M-E3/61T |  S1M-M3/61T |
|  S1M-M3/61T |  S1M0V043B1J8100 |  S1M8656A01-F0T0 |  S1M8662A01-Z070 |  S1M8691X01-J070 |
|  S1M8732X01-Y070 |  S1M8837X01 |  S1M8837X01-N0T0 |  S1MB-13-F |  S1MHE3/61T |
|  S1MHE3/61T |  S1MHE3_A/H |  S1MHE3_A/H |  S1MHE3_A/I |  S1MSP1-F |
|  S1MSWF-7 |  S1MSWFQ-7 |  S9S08SG16CTL |  SS2PH10-E3/85A |  STW8C2SB |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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